SiT8209
High Frequency, Ultra Performance Oscillator

SiTime™
The Smart Timing Choice™

Features

- Any frequency between 80.000001 and 220 MHz accurate to 6 decimal places
- 100% pin-to-pin drop-in replacement to quartz-based oscillators
- Ultra low phase jitter: 0.5 ps (12 kHz to 20 MHz)
- Frequency stability as low as ±10 PPM
- Industrial or extended commercial temperature range
- LVCMOS/LVTTL compatible output
- Standby or output enable modes
- Standard 4-pin packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm^2
- Outstanding silicon reliability of 2 FIT or 500 million hour MTBF
- Pb-free, RoHS and REACH compliant
- Ultra short lead time

Applications

- SATA, SAS, Ethernet, 10-Gigabit Ethernet, SONET, PCI Express, video, Wireless
- Computing, storage, networking, telecom, industrial control

EXPRESS SAMPLES   GREEN SOLUTIONS   QUARTZ FREE

Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Output Frequency Range	f	80.000001	–	220	MHz	
Frequency Stability	F_stab	-10	–	+10	PPM	Inclusive of Initial tolerance at 25 °C, and variations over operating temperature, rated power supply voltage and load
		-20	–	+20	PPM	
		-25	–	+25	PPM	
		-50	–	+50	PPM	
Operating Temperature Range	T_use	-20	–	+70	°C	Extended Commercial
		-40	–	+85	°C	Industrial
Supply Voltage	Vdd	1.71	1.8	1.89	V	Supply voltages between 2.5V and 3.3V can be supported. Contact SiTime for guaranteed performance specs for supply voltages not specified in this table.
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.97	3.3	3.63	V	
Current Consumption	Idd	–	34	36	mA	No load condition, f = 100 MHz, Vdd = 2.5V, 2.8V or 3.3V
		–	30	33	mA	No load condition, f = 100 MHz, Vdd = 1.8V
OE Disable Current	I_OD	–	–	31	mA	Vdd = 2.5V, 2.8V or 3.3V, OE = GND, output is Weakly Pulled Down
		–	–	30	mA	Vdd = 1.8 V. OE = GND, output is Weakly Pulled Down
Standby Current	I_std	–	–	70	µA	Vdd = 2.5V, 2.8V or 3.3V, ST̄ = GND, output is Weakly Pulled Down
		–	–	10	µA	Vdd = 1.8 V. ST̄ = GND, output is Weakly Pulled Down
Duty Cycle	DC	45	–	55	%	f <= 165 MHz, all Vdds.
		40	–	60	%	f > 165 MHz, all Vdds.
Rise/Fall Time	Tr, Tf	–	1.2	2	ns	15 pF load, 10% - 90% Vdd
Output Voltage High	VOH	90%	–	–	Vdd	IOH = -6 mA, IOL = 6 mA, (Vdd = 3.3V, 2.8V, 2.5V) IOH = -3 mA, IOL = 3 mA, (Vdd = 1.8V)
Output Voltage Low	VOL	–	–	10%	Vdd	
Input Voltage High	VIH	70%	–	–	Vdd	Pin 1, OE or ST̄
Input Voltage Low	VIL	–	–	30%	Vdd	Pin 1, OE or ST̄
Input Pull-up Impedance	Z_in	–	100	250	kΩ	Pin 1, OE logic high or logic low, or ST̄ logic high
		2	–	–	MΩ	Pin 1, ST̄ logic low
Startup Time	T_start	–	7	10	ms	Measured from the time Vdd reaches its rated minimum value
OE Enable/Disable Time	T_oe	–	–	115	ns	f = 80 MHz, For other frequencies, T_oe = 100 ns + 3 cycles
Resume Time	T_resume	–	–	10	ms	In standby mode, measured from the time ST̄ pin crosses 50% threshold. Refer to Figure 5.
RMS Period Jitter	T_jitt	–	1.5	2	ps	f = 156.25 MHz, Vdd = 2.5V, 2.8V or 3.3V
		–	2	3	ps	f = 156.25 MHz, Vdd = 1.8V
RMS Phase Jitter (random)	T_phj	–	0.5	1	ps	f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz
First year Aging	F_aging	-1.5	–	+1.5	PPM	25°C
10-year Aging		-5	–	+5	PPM	25°C

Note:
1. All electrical specifications in the above table are specified with 15 pF ±10% output load and for all Vdd(s) unless otherwise stated.
2. Contact SiTime for custom drive strength to drive higher or multiple load, or SoftEdge™ option for EMI reduction.

Pin Configuration

Pin	Symbol		Functionality
1	OE/$\overline{\text{ST}}$	Output Enable	H or Open[3]: specified frequency output L: output is high impedance. Only output driver is disabled.
		Standby	H or Open[3]: specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.
2	GND	Power	Electrical ground
3	OUT	Output	Oscillator output
4	VDD	Power	Power supply voltage

Top View

OE/$\overline{\text{ST}}$ [1]   [4] VDD

GND [2]   [3] OUT
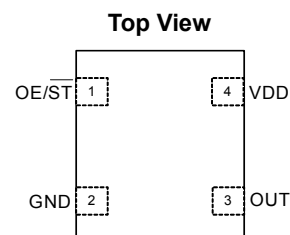
Note:

3. A pull-up resistor of <10 kΩ between OE/$\overline{\text{ST}}$ pin and Vdd is recommended in high noise environment

Absolute Maximum

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	–	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	–	260	°C

Thermal Consideration

Package	θJA, 4 Layer Board (°C/W)	θJA, 2 Layer Board (°C/W)	θJC, Bottom (°C/W)
7050	191	263	30
5032	97	199	24
3225	109	212	27
2520	117	222	26

Environmental Compliance

Parameter	Condition/Test Method
Mechanical Shock	MIL-STD-883F, Method 2002
Mechanical Vibration	MIL-STD-883F, Method 2007
Temperature Cycle	JESD22, Method A104
Solderability	MIL-STD-883F, Method 2003
Moisture Sensitivity Level	MSL1 @ 260°C

Phase Noise Plot

Integrated random phase jitter (12kHz to 20MHz): 0.49 ps,RMS
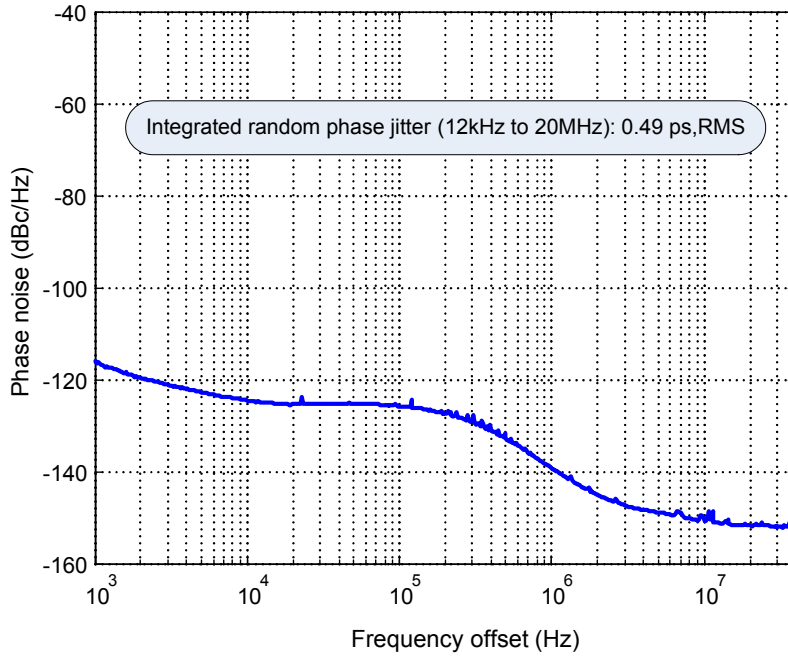
Figure 1. Phase Noise, 156.25 MHz, 3.3V, LVCMOS Output

Test Circuit and Waveform
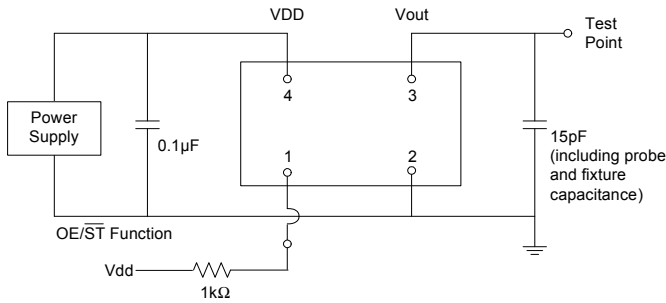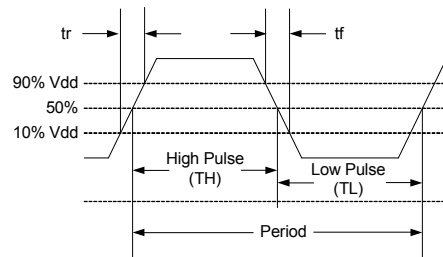

Figure 2. Test Circuit

Figure 3. Waveform

Notes:
4. Duty Cycle is computed as Duty Cycle = TH/Period.
5. SiT8209 supports the configurable duty cycle feature. For custom duty cycle at any given frequency, contact SiTime.
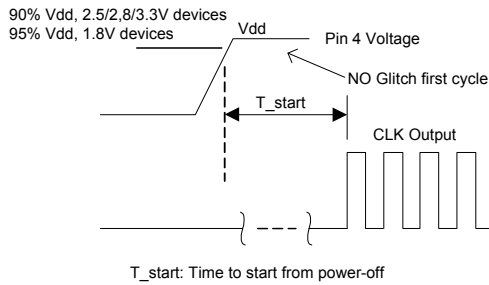
Timing Diagram

T_start: Time to start from power-off

Figure 4. Startup Timing (OE/ST Mode)

T_resume: Time to resume from ST
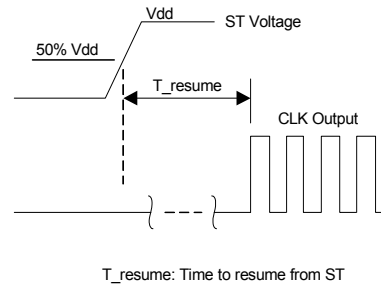
Figure 5. Standby Resume Timing (ST Mode Only)

T_OE: Time to re-enable the clock output
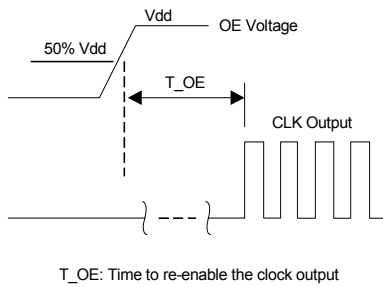
Figure 6. OE Enable Timing (OE Mode Only)

T_OE: Time to put the output drive in High Z mode
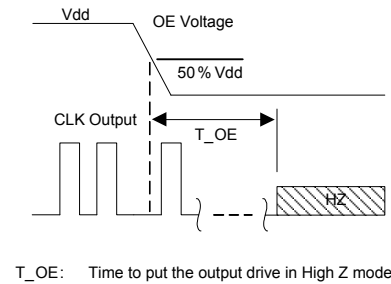
Figure 7. OE Disable Timing (OE Mode Only)

Note:
6. SiT8209 supports NO RUNT pulses and No glitches during startup or resume.
7. SiT8209 supports gated output which is accurate within rated frequency stability from the first cycle.

Performance Plots
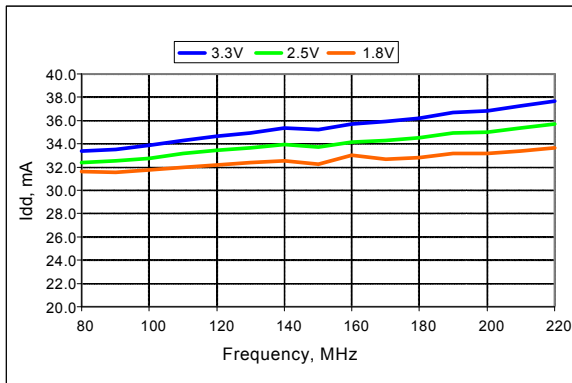
Figure 8. Idd vs Frequency
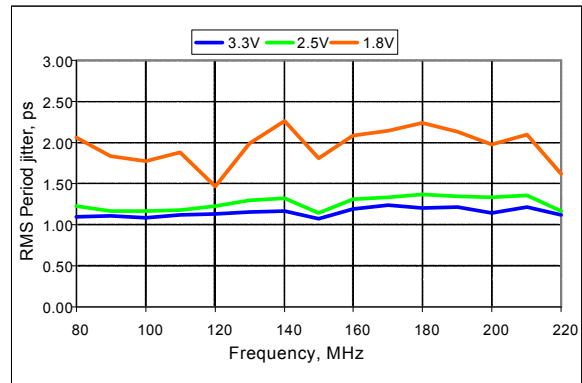
Figure 9. RMS Period Jitter vs Frequency
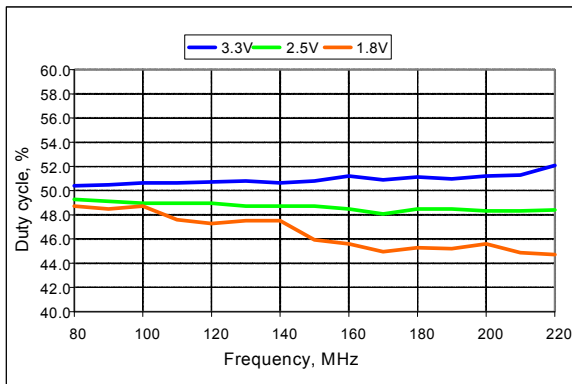
Figure 10. Duty Cycle vs Frequency
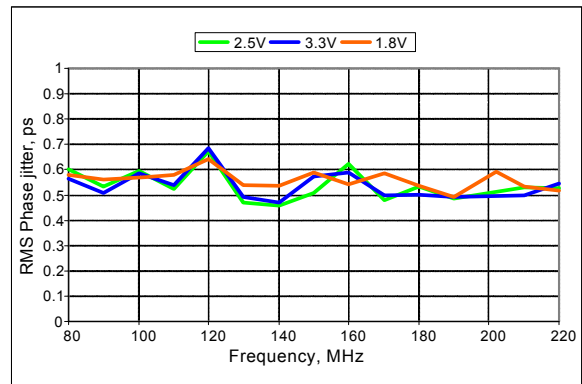
Figure 11. RMS Phase Jitter vs Frequency
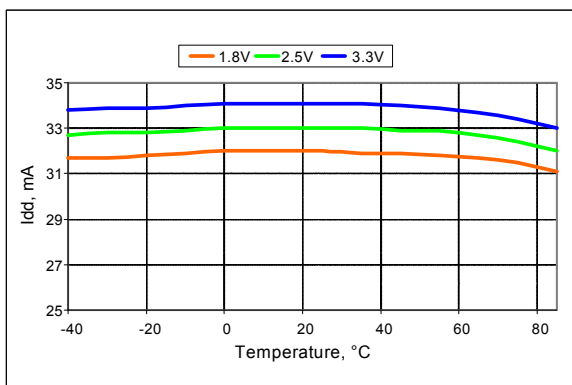
Figure 12. Idd vs Temperature, 100 MHz Output
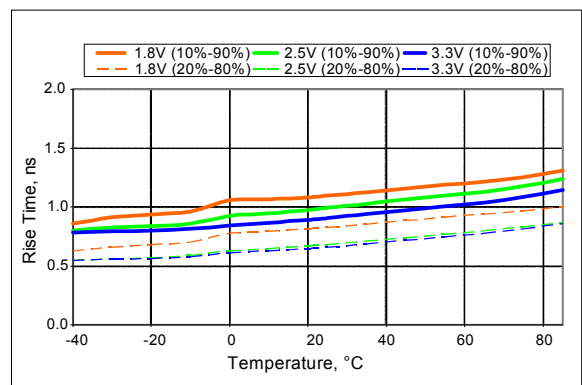
Figure 13. Rise Time vs Temperature, 100 MHz Output

Note:
8. All plots are measured with 15pF load at room temperature, unless otherwise stated.
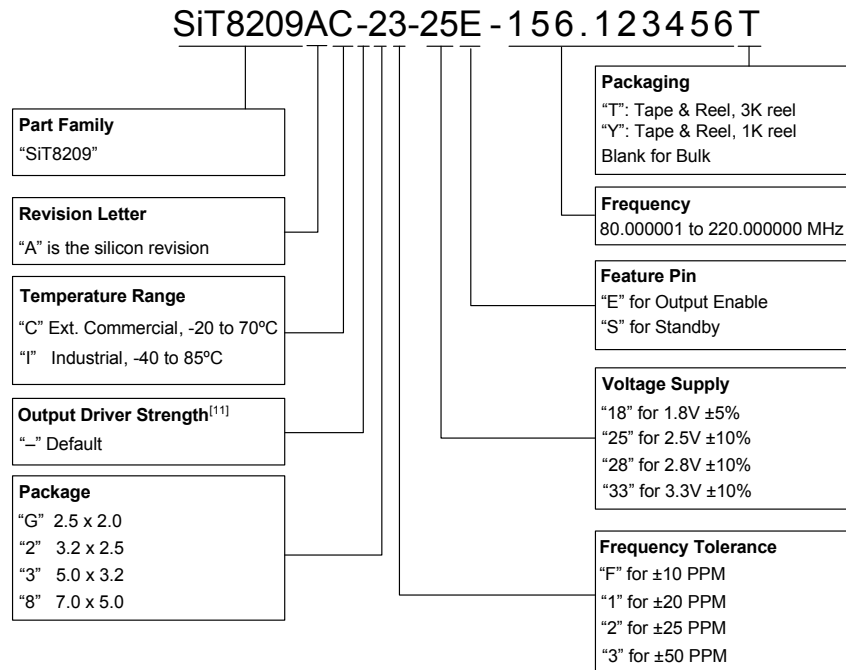
Dimensions and Patterns

Package Size – Dimensions (Unit: mm) [9]	Recommended Land Pattern (Unit: mm) [10]
2.7 x 2.4 x 0.75 mm (100% compatible with 2.5 x 2. 0 mm footprint)	
3.2 x 2.5 x 0.75 mm	
5.0 x 3.2 x 0.75 mm	
7.0 x 5.0 x 0.90 mm	

Notes:

9. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
10. A capacitor of value 0.1 µF between Vdd and GND is recommended.

Ordering Information

The Part No. Guide is for reference only. To customize and build an exact part number, use the SiTime Part Number Generator.

SiT8209AC-23-25E - 156.123456T

Part Family
"SiT8209"

Revision Letter
"A" is the silicon revision

Temperature Range
"C" Ext. Commercial, -20 to 70ºC
"I" Industrial, -40 to 85ºC

Output Driver Strength[11]
"–" Default

Package
"G" 2.5 x 2.0
"2" 3.2 x 2.5
"3" 5.0 x 3.2
"8" 7.0 x 5.0

Packaging
"T": Tape & Reel, 3K reel
"Y": Tape & Reel, 1K reel
Blank for Bulk

Frequency
80.000001 to 220.000000 MHz

Feature Pin
"E" for Output Enable
"S" for Standby

Voltage Supply
"18" for 1.8V ±5%
"25" for 2.5V ±10%
"28" for 2.8V ±10%
"33" for 3.3V ±10%

Frequency Tolerance
"F" for ±10 PPM
"1" for ±20 PPM
"2" for ±25 PPM
"3" for ±50 PPM

Note:

11. Contact SiTime for custom drive strength to drive higher or multiple load, or SoftEdge™ option for EMI reduction.

Additional Information

Document	Description	Download Link
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info	http://www.sitime.com/component/docman/doc_download/85-manufacturing-notes-for-sitime-oscillators
Qualification Reports	RoHS report, reliability reports, composition reports	http://www.sitime.com/support/quality-and-reliability
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	http://www.sitime.com/support/performance-measurement-report
Termination Techniques	Termination design recommendations	http://www.sitime.com/support/application-notes
Layout Techniques	Layout recommendations	http://www.sitime.com/support/application-notes